

20 V, 6 A PNP low V_{CEsat} (BISS) transistor Rev. 01 — 13 April 2010

Product data sheet

1. **Product profile**

1.1 General description

PNP low V_{CEsat} Breakthrough In Small Signal (BISS) transistor, encapsulated in an ultra thin SOT1061 leadless small Surface-Mounted Device (SMD) plastic package with medium power capability.

NPN complement: PBSS4620PA.

1.2 Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors
- Exposed heat sink for excellent thermal and electrical conductivity
- Leadless small SMD plastic package with medium power capability

1.3 Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-20	V
I _C	collector current		-	-	-6	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	-7	А
R _{CEsat}	collector-emitter saturation resistance	I _C = -6 A; I _B = -300 mA	<u>[1]</u> _	39	58	mΩ

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.



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2. Pinning information

Table 2.	Pinning	
Pin	Description	Simplified outline Graphic symbol
1	base	
2	emitter	3
3	collector	
		1 2 sym013
		Transparent top view

3. Ordering information

Table 3. Ordering information				
Type number	Package			
	Name	Description	Version	
PBSS5620PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; three terminals; body 2 \times 2 \times 0.65 mm	SOT1061	

4. Marking

Table 4.	Marking codes	
Type num	ber	Marking code
PBSS562	OPA	AA

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		• • •	-		
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	-20	V
V _{CEO}	collector-emitter voltage	open base	-	-20	V
V _{EBO}	emitter-base voltage	open collector	-	-7	V
I _C	collector current		-	-6	А
I _{CM}	peak collector current	single pulse; $t_p \leq 1 ms$	-	-7	A
I _B	base current		-	-600	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	500	mW
			[2] _	1	W
			[3]	1.4	W
			<u>[4]</u> _	2.1	W

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Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

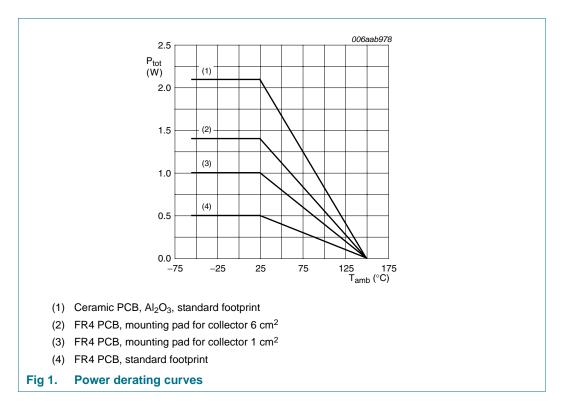
Symbol	Parameter	Conditions	Min	Max	Unit
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	<u>[1]</u> _	-	250	K/W
	junction to ambient		[2] _	-	125	K/W
			[3]	-	90	K/W
			[4]	-	60	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

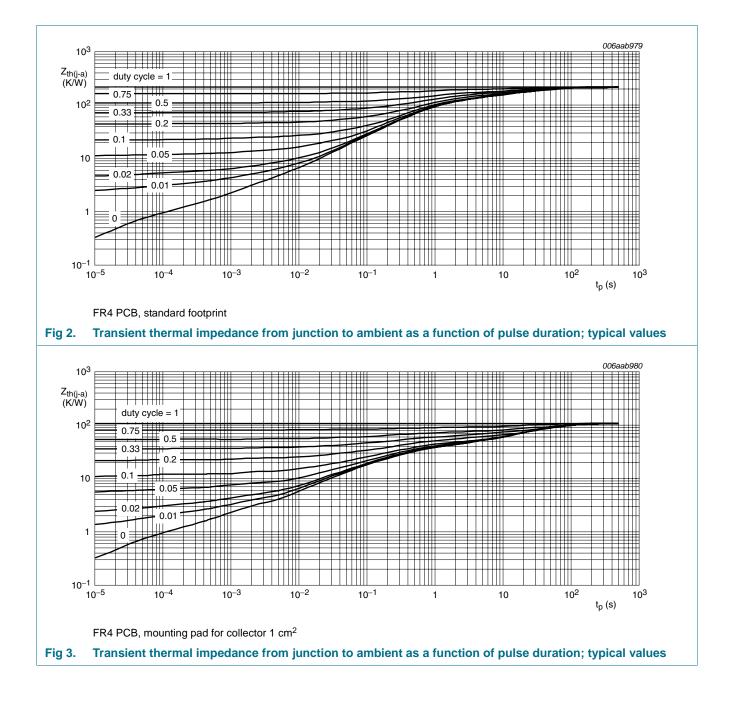
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

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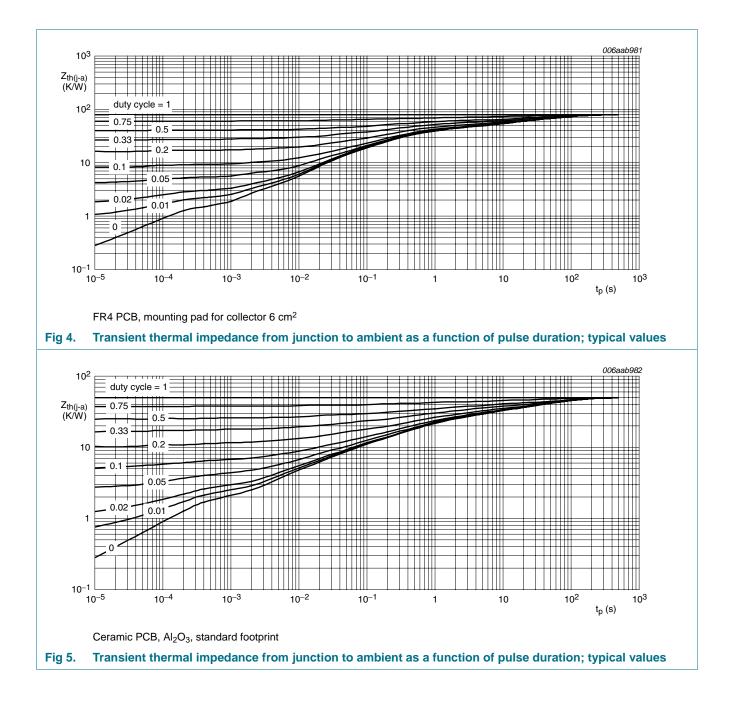
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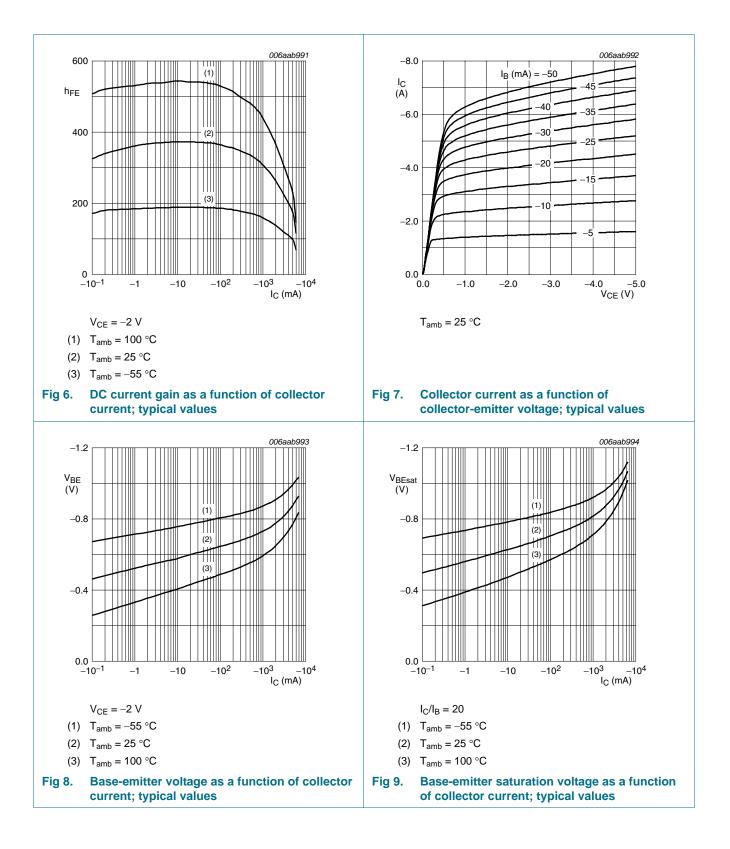
20 V, 6 A PNP low V_{CEsat} (BISS) transistor

7. Characteristics

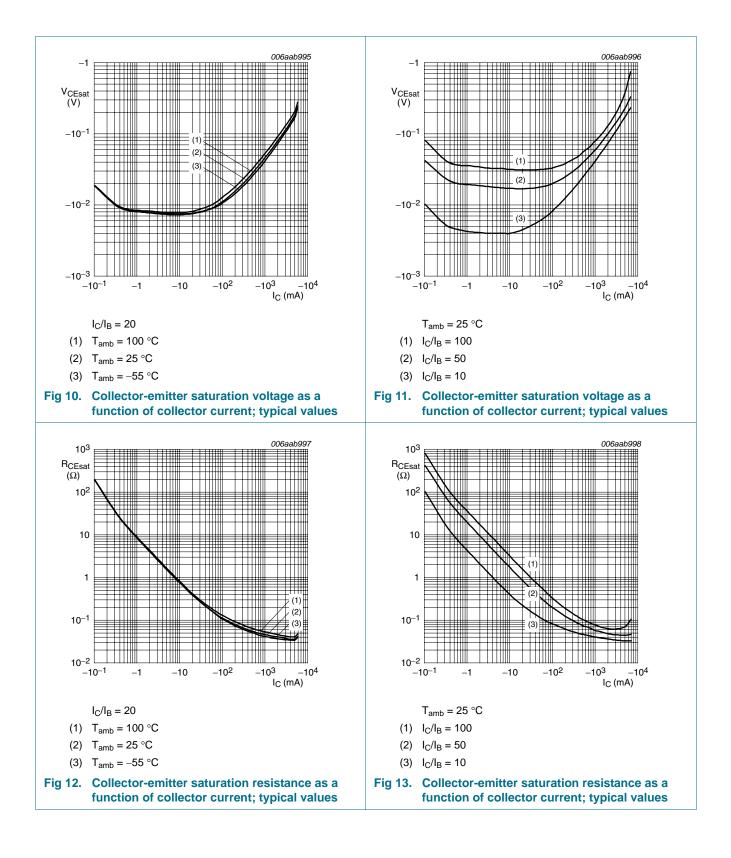
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base	$V_{CB} = -16 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
	cut-off current	$V_{CB} = -16 \text{ V}; \text{ I}_{E} = 0 \text{ A};$ T _j = 150 °C	-	-	-50	μΑ
I _{CES}	collector-emitter cut-off current	$V_{CE} = -16 \text{ V}; V_{BE} = 0 \text{ V}$	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -2 V$	<u>[1]</u>			
		I _C = -0.5 A	230	345	-	
		$I_{\rm C} = -1$ A	220	320	-	
		I _C = -2 A	190	275	-	
		$I_{\rm C} = -6 {\rm A}$	110	155	-	
OLOUI	collector-emitter	$I_{C} = -0.5 \text{ A}; I_{B} = -50 \text{ mA}$	<u>[1]</u> -	-25	-40	mV
	saturation voltage	$I_{C} = -1 \text{ A}; I_{B} = -50 \text{ mA}$	<u>[1]</u> -	-50	-80	mV
		$I_{C} = -1 \text{ A}; I_{B} = -10 \text{ mA}$	<u>[1]</u> -	-80	-130	mV
		$I_{C} = -2 \text{ A}; I_{B} = -20 \text{ mA}$	<u>[1]</u> -	-135	-210	mV
		$I_{C} = -3 \text{ A}; I_{B} = -30 \text{ mA}$	<u>[1]</u> -	-215	-325	mV
		$I_{C} = -4 \text{ A}; I_{B} = -400 \text{ mA}$	<u>[1]</u> -	-150	-230	mV
		$I_{C} = -6 \text{ A}; I_{B} = -300 \text{ mA}$	<u>[1]</u> -	-235	-350	mV
R _{CEsat}	collector-emitter saturation resistance	$I_{C} = -6 \text{ A}; I_{B} = -300 \text{ mA}$	<u>[1]</u> _	39	58	mΩ
V _{BEsat}	base-emitter	$I_{C} = -1 \text{ A}; I_{B} = -10 \text{ mA}$	<u>[1]</u> _	-0.75	-0.9	V
	saturation voltage	$I_{C} = -6 \text{ A}; I_{B} = -300 \text{ mA}$	<u>[1]</u> _	-1.03	-1.1	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I_C = -2 A	<u>[1]</u> _	-0.76	-0.9	V
t _d	delay time	V_{CC} = -9 V; I_C = -2 A;	-	19	-	ns
t _r	rise time	I _{Bon} = -0.1 A; I _{Boff} = 0.1 A	-	59	-	ns
t _{on}	turn-on time	'B0# - 0.1 A	-	78	-	ns
t _s	storage time		-	265	-	ns
t _f	fall time		-	55	-	ns
t _{off}	turn-off time		-	320	-	ns
f _T	transition frequency	$V_{CE} = -10 \text{ V};$ $I_{C} = -100 \text{ mA};$ f = 100 MHz	50	80	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = i _e = 0 A; f = 1 MHz	-	75	90	pF

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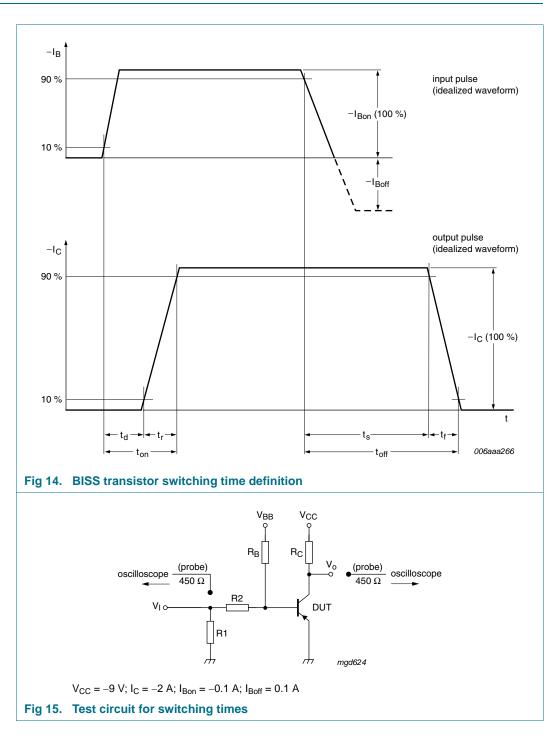


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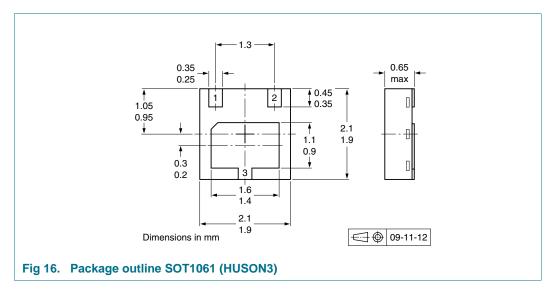
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8. Test information



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9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

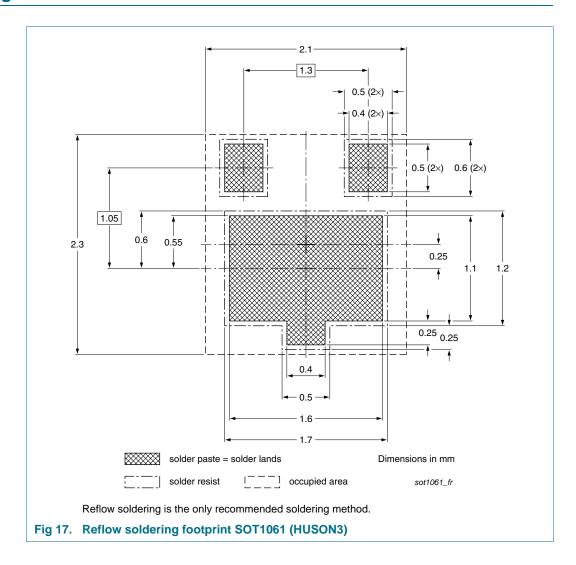
Type number	Package	Description	Packing quantity
			3000
PBSS5620PA	SOT1061	4 mm pitch, 8 mm tape and reel	-115

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

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11. Soldering



Product data sheet

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12. Revision history

Table 9. Revision hist	Revision history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5620PA_1	20100413	Product data sheet	-	-

20 V, 6 A PNP low V_{CEsat} (BISS) transistor

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions"

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